## NSN 5962-01-371-1029

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View Online at https://aerobasegroup.com/nsn/5962-01-371-1029

Body Length:
0.560 inches
Body Width:
0.458 inches
Body Height:
0.120 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and erasable and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
23 input
Case Outline Source And Designator:
C-12 mil-m-38510
Current Rating Per Characteristic:
80.00 milliamperes forward current, nonrepetitive, peak total value minor
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
6.2 volts power source
Memory Device Type:
Eeprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 leadless
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

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